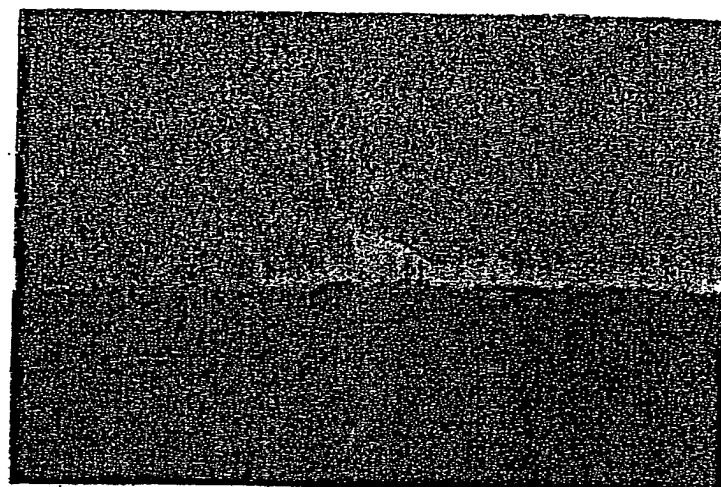


Fig. 1

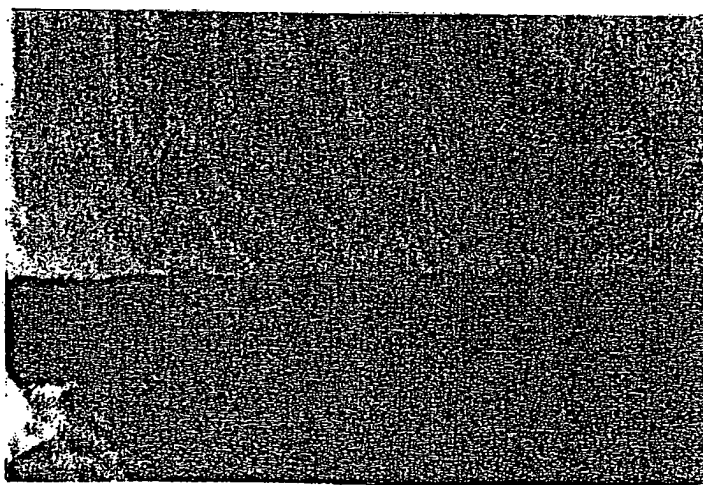


10 nm

a-Si:H/ITO/SiOx/PET

a-Si:H PE-CVD SiH₄/H₂ 50sccm 200mTorr
Ts = 120° C RF power 20W

Fig. 2



10 nm

a-Si/ITO/SiOx/PET

a-Si DC sputter Ar 50sccm 5mTorr
Ts = 80° C DC power 1000W

Fig. 3

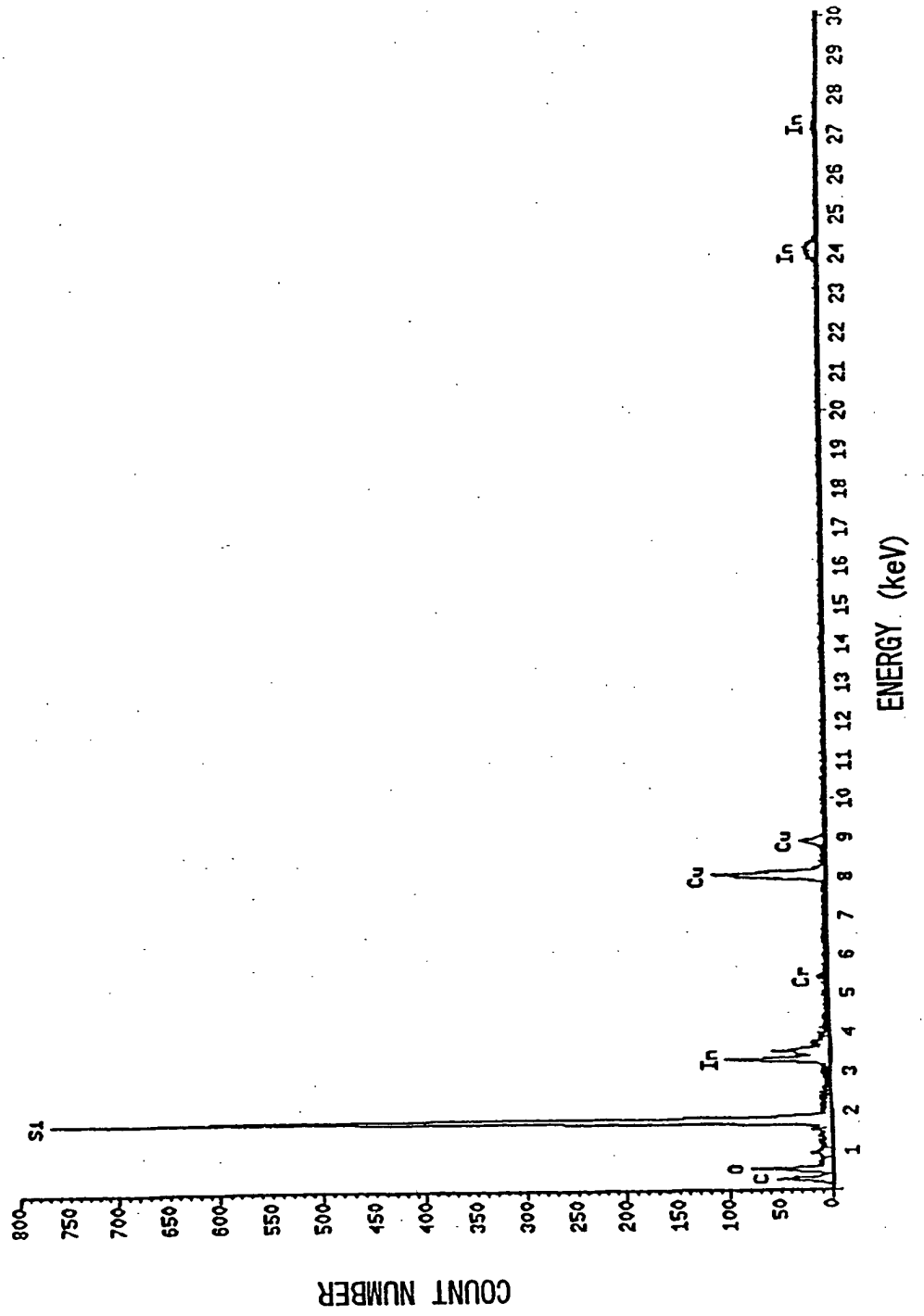


Fig. 4

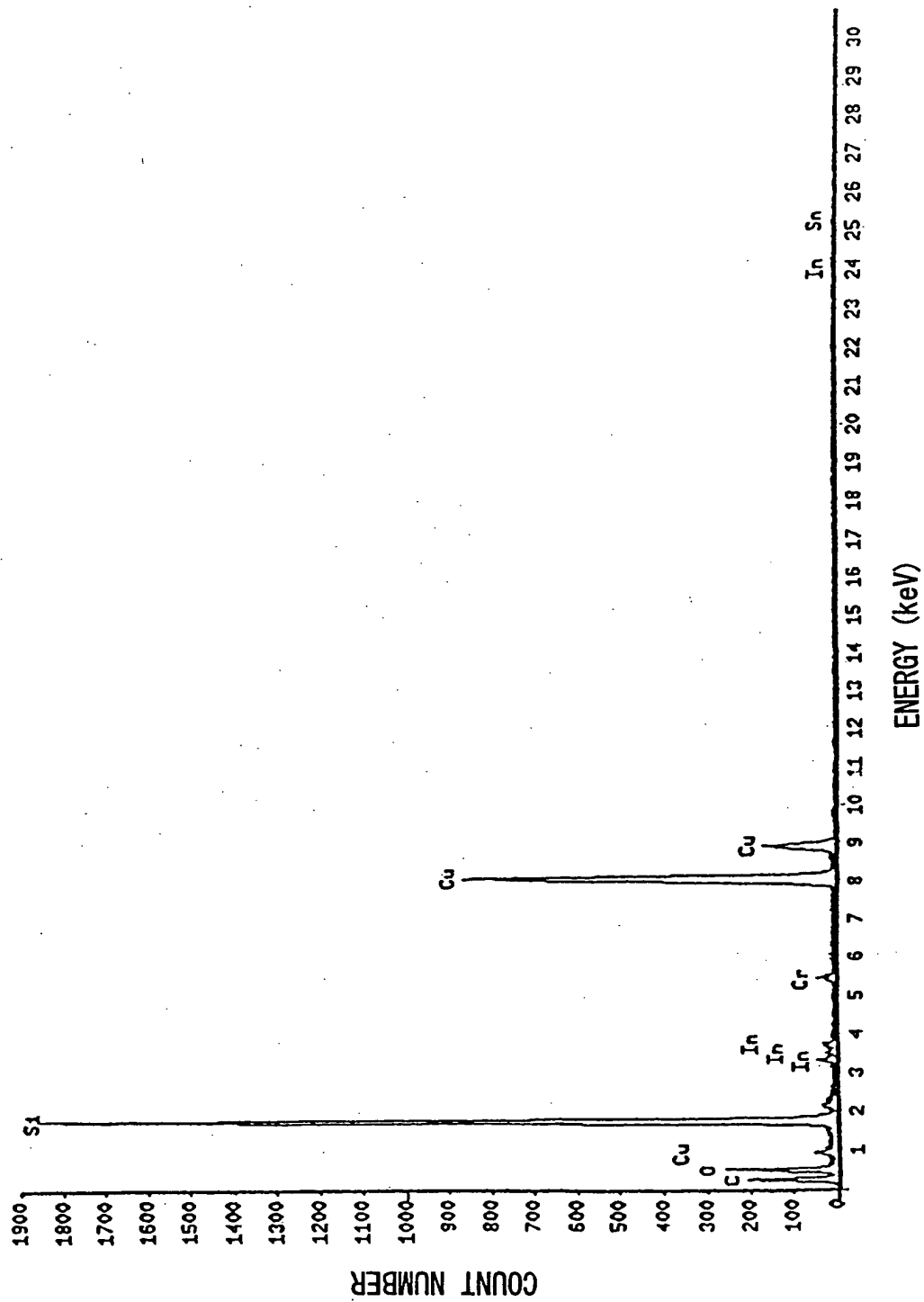


Fig. 5

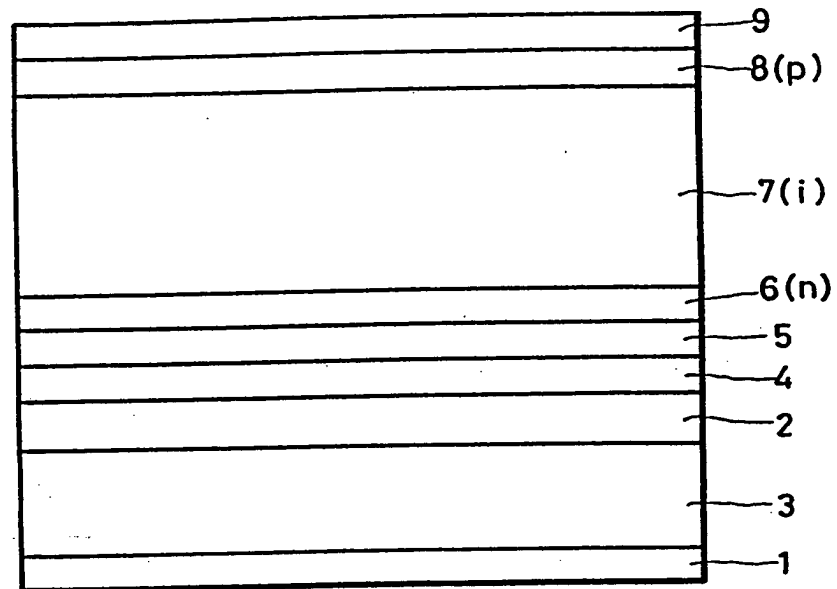


Fig. 6

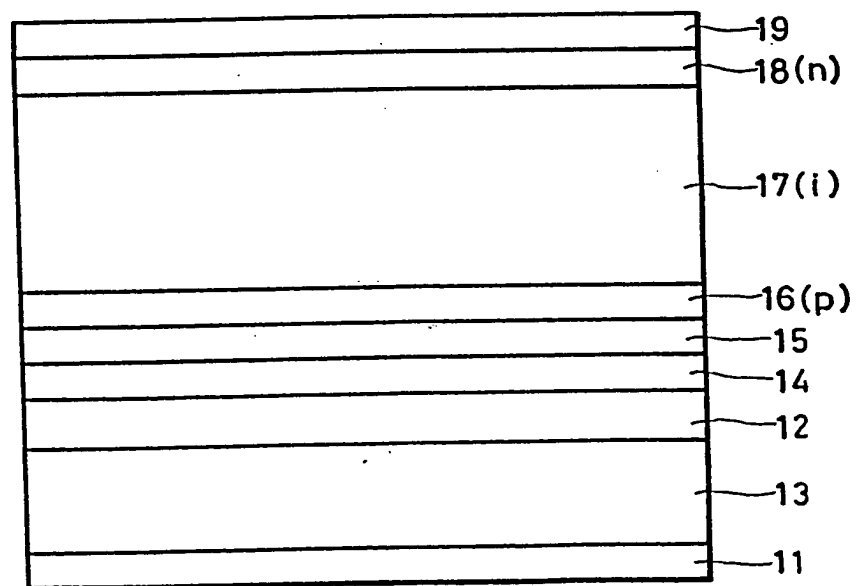


Fig. 7

